MICROWAVE CORPORATION

Designer's Kit
Available

WIDEBAND FIXED ATTENUATOR FAMILY, DC - 50 GHz
HMC650 / 651 / 652 / 653 / 654 / 655 / 656 / 657 / 658

PASSIVES - CHIP

2

Typical Applications

The HMC650 through HMC658 are ideal for:

- Fiber Optics
- Microwave Radio
- Military & Space Hybrids
- Test & Measurement
- Scientific Instruments
- RF / Microwave Circuit Prototyping

Features

Wide Bandwidth: DC - 50 GHz

9 Attenuator Products:
0, 2, 3, 4, 6, 10, 15, & 20 dB Fixed Levels

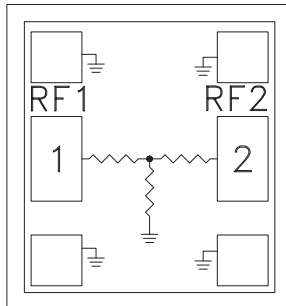Power Handling: +25 dBm

HMC651 & HMC658
Die Size: 0.57 x 0.45 x 0.1 mm

HMC650, HMC652, HMC653, HMC654
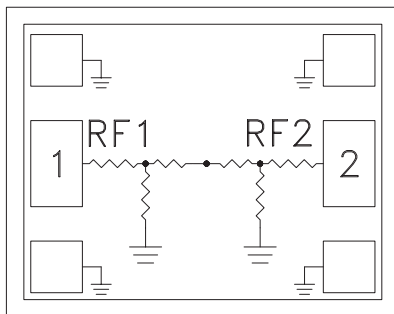HMC655, HMC656 & HMC657
Die Size: 0.42 x 0.45 x 0.1 mm

Included in the HMC-DK006 Designer's Kit

Functional Diagrams

HMC650, HMC652, HMC653, HMC654,
HMC655, HMC656 & HMC657

HMC651, HMC658

General Description

The HMC650 / 651 / 652 / 653 / 654 / 655 / 656 / 657 / 658 are a line of wideband fixed value 50 Ohm matched attenuator chips which offer relative attenuation levels of 0, 2, 3, 4, 6, 10, 15 and 20 dB. These passive though-lines and attenuators are ideal for microstrip, hybrid, and multi-chip module applications where extremely flat attenuation, and excellent VSWR vs. frequency are required.

These wideband attenuators feature low inductance on-chip vias, and require no additional ground connections. The HMC650 through HMC658 are backside metallized with gold, and are suitable for eutectic or epoxy die attach. Each of the 9 products can be purchased individually by their respective part number or in a set of 10 each in the HMC-DK006 Fixed Attenuator Chip Designer's Kit.

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WIDEBAND FIXED ATTENUATOR FAMILY, DC - 50 GHz
HMC650 / 651 / 652 / 653 / 654 / 655 / 656 / 657 / 658

### *Electrical Specifications, T_A = +25° C, 50 Ohm system [1]*

Part Number	Attenuator Value	Return Loss	Attenuation Tolerance	Return Loss	Attenuation Tolerance	Units
		DC - 25		25 - 50		GHz
HMC650	Thru Line (short)	20.3	±0.2	12.4	±0.8	dB
HMC651	Thru Line (long)	19.0	±0.3	12.3	±0.9	dB
HMC652	2 dB	22.0	±0.2	15.3	±0.6	dB
HMC653	3 dB	23.0	±0.2	22.1	±0.5	dB
HMC654	4 dB	20.5	±0.2	22.4	±0.5	dB
HMC655	6 dB	16.5	±0.2	17.0	±0.6	dB
HMC656	10 dB	16.9	±0.1	18.8	±0.7	dB
HMC657	15 dB	20.0	±0.4	19.7	±1.3	dB
HMC658	20 dB	17.5	±0.5	16.2	±1.6	dB

RF Data with Wire Bonds [1]

Attenuation vs. Temperature
HMC652, HMC653, HMC654, HMC655
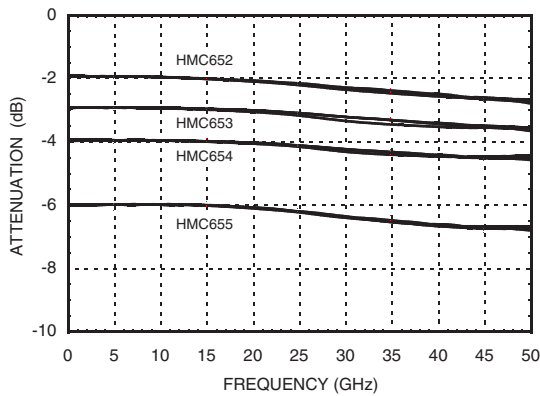
Attenuation vs. Temperature
HMC656, HMC657, HMC658
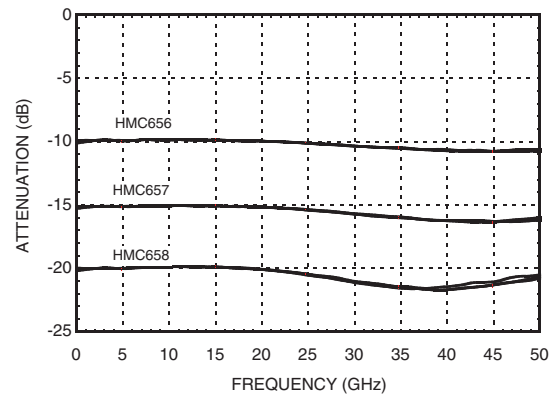
Return Loss
HMC652, HMC653, HMC654, HMC655

Return Loss
HMC656, HMC657, HMC658
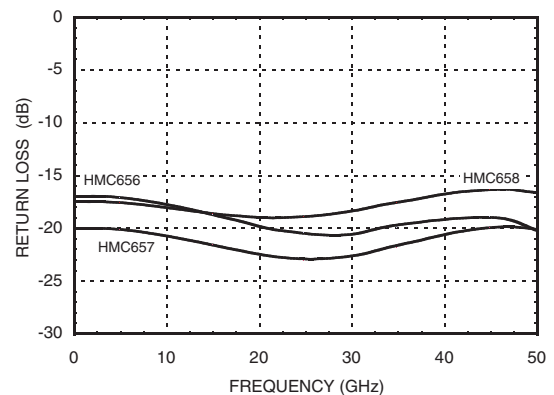
[1] Data taken with die mounted to plate and RF probed through two 1 mil diameter wire bonds.

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WIDEBAND FIXED ATTENUATOR FAMILY, DC - 50 GHz
HMC650 / 651 / 652 / 653 / 654 / 655 / 656 / 657 / 658

PASSIVES - CHIP
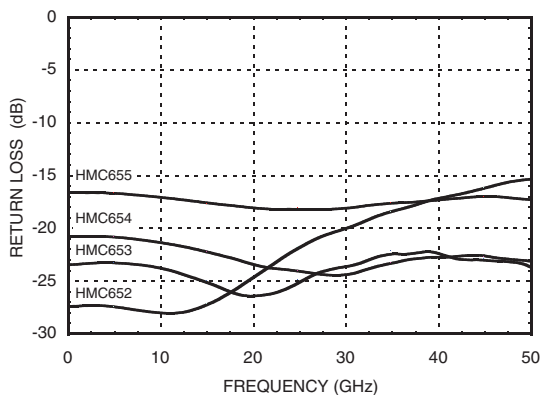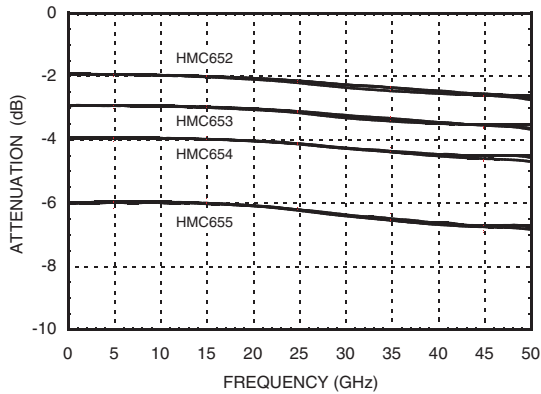
2

RF Data with Ribbon Bonds [2]

Attenuation vs. Temperature
HMC652, HMC653, HMC654, HMC655

Attenuation vs. Temperature
HMC656, HMC657, HMC658

Return Loss
HMC652, HMC653, HMC654, HMC655

Return Loss
HMC656, HMC657, HMC658

[2] Data taken with die mounted to plate and RF probed through two 3 x 0.5 mil ribbon bonds.

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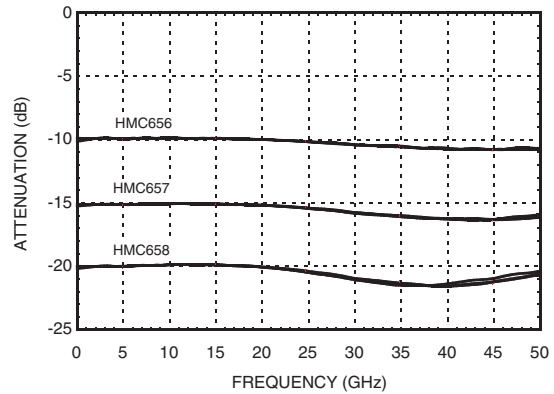
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WIDEBAND FIXED ATTENUATOR FAMILY, DC - 50 GHz
HMC650 / 651 / 652 / 653 / 654 / 655 / 656 / 657 / 658
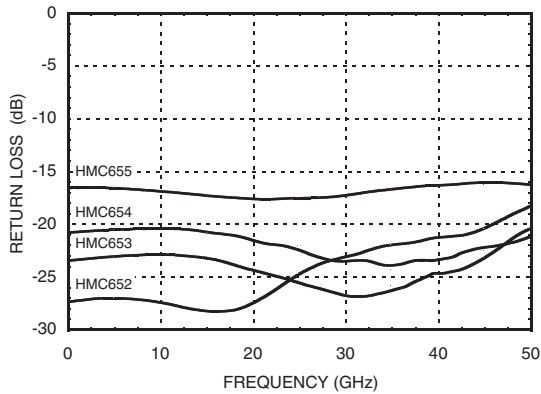
RF Data Die Only [3]

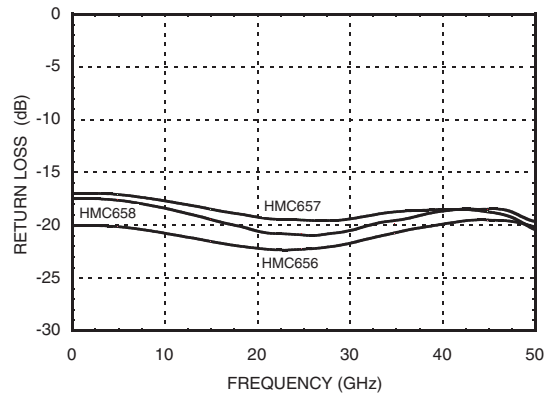**Attenuation vs. Temperature**
HMC652, HMC653, HMC654, HMC655

Attenuation vs. Temperature
HMC656, HMC657, HMC658

Return Loss
HMC652, HMC653, HMC654, HMC655
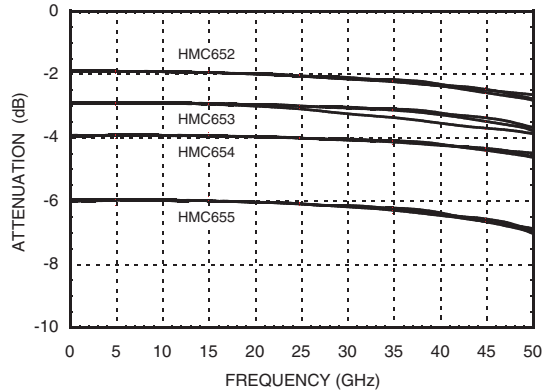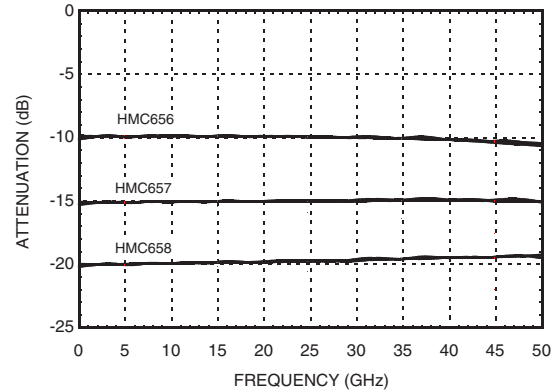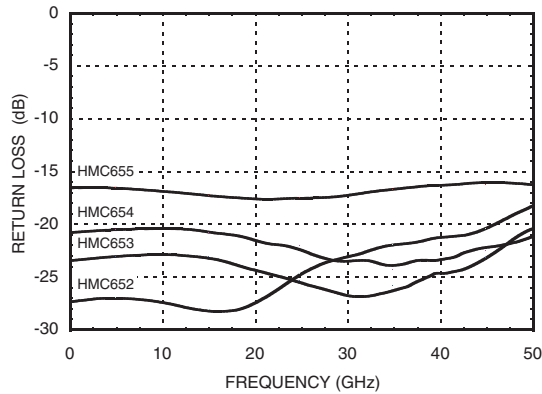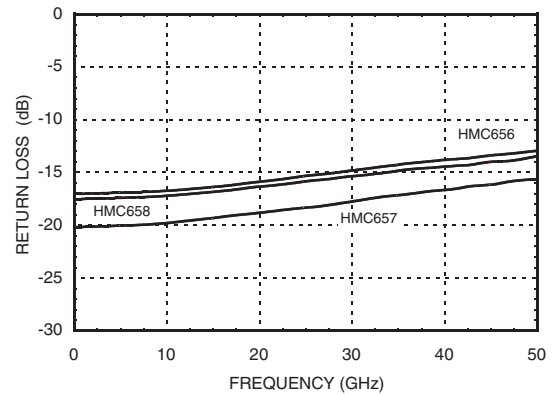

Return Loss
HMC656, HMC657, HMC658

Absolute Maximum Ratings

| Part Number	HMC650	HMC651	HMC652	HMC653	HMC654	HMC655	HMC656	HMC657	HMC658	Units
RF Input Power (CW)	N/A	N/A	27	26	25	26	25	25	25	dBm
DC Voltage Terminated	N/A	N/A	5.6	5.2	4.9	5.2	4.9	4.4	4.8	V
DC Voltage Open	N/A	N/A	5.6	5.1	4.6	6.0	5.3	4.6	4.9	V
Storage Temperature	-65 to +150									°C
Operating Temperature	-55 to +85									°C

ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

[3] Data taken with die mounted to a plate and RF probed directly on die.

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PASSIVES - CHIP

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Outline Drawing
HMC650, HMC652, HMC653, HMC654, HMC655, HMC656 HMC657
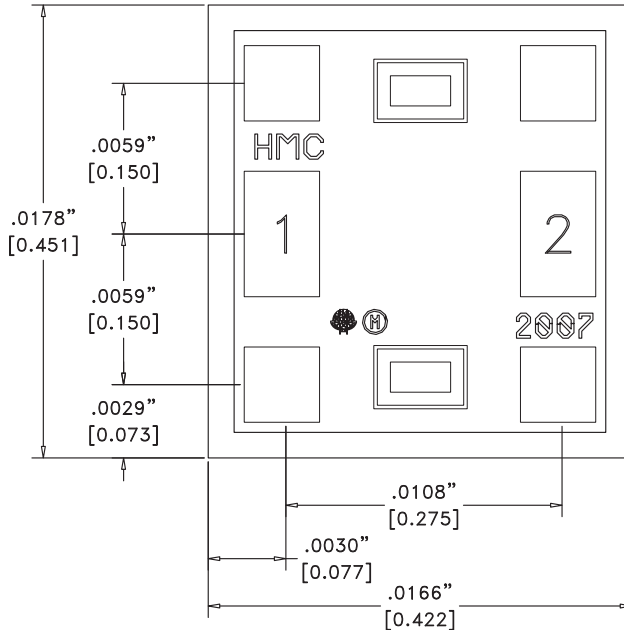
Die Packaging Information [1]

Standard	Alternate
GP-5 (Gel Pack)	[2]

[1] Refer to the "Packaging Information" section for die packaging dimensions.
[2] For alternate packaging information contact Hittite Microwave Corporation.

NOTES:
1. ALL DIMENSIONS ARE IN INCHES (MILLIMETERS).
2. TYPICAL BOND PAD IS .004" SQUARE.
3. TYPICAL BOND PAD SPACING IS .006" CENTER TO CENTER EXCEPT AS NOTED.
4. BACKSIDE METALIZATION: GOLD
5. BACKSIDE METAL IS GROUND
6. BOND PAD METALIZATION: GOLD
7. DO NOT BOND ON TOP OF GROUND VIAS
8. OVERALL DIE SIZE ±0.002"

Outline Drawing
HMC651 & HMC658
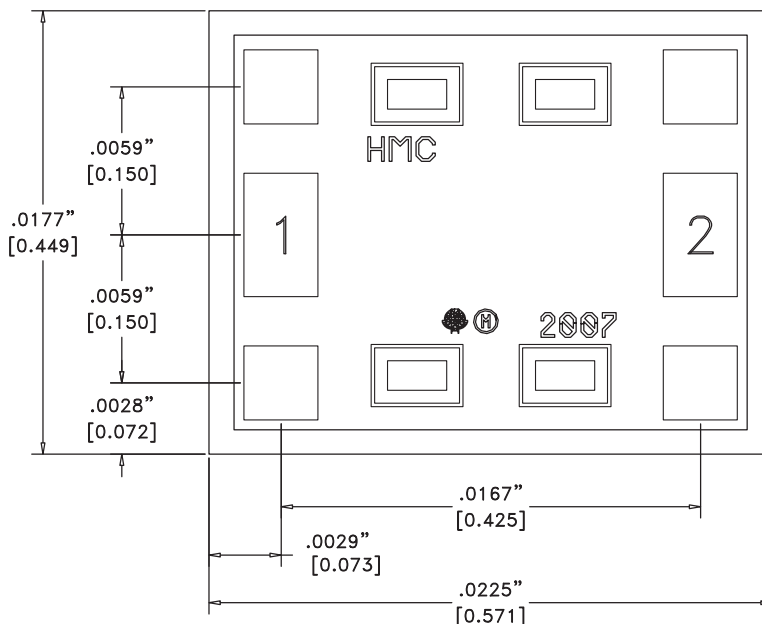
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Pad Descriptions

Pad Number	Function	Description	Interface Schematic
1, 2	RF1, RF2	This pad is DC coupled and matched to 50 Ohms. Use DC Blocking capacitors if the input / output signals have non-zero DC potential	
	GND	Die bottom must be connected to RF ground.	GND

Assembly Diagram

1 MIL GOLD WIRE

50 OHM TRANSMISSION LINE

HMC

2007

3 MIL NOMINAL GAP

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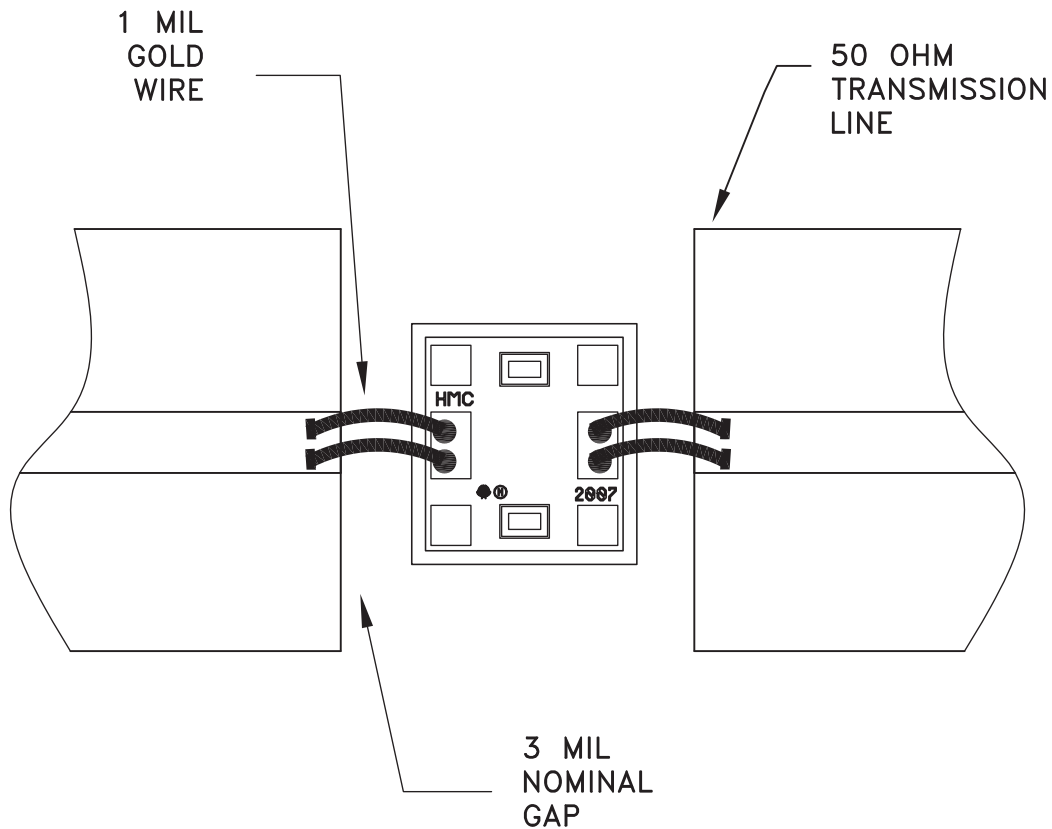
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Mounting & Bonding Techniques for Millimeterwave GaAs MMICs

The die should be attached directly to the ground plane eutectically or with conductive epoxy (see HMC general Handling, Mounting, Bonding Note).

50 Ohm Microstrip transmission lines on 0.127mm (5 mil) thick alumina thin film substrates are recommended for bringing RF to and from the chip (Figure 1). If 0.254mm (10 mil) thick alumina thin film substrates must be used, the die should be raised 0.150mm (6 mils) so that the surface of the die is coplanar with the surface of the substrate. One way to accomplish this is to attach the 0.102mm (4 mil) thick die to a 0.150mm (6 mil) thick molybdenum heat spreader (moly-tab) which is then attached to the ground plane (Figure 2).

Microstrip substrates should brought as close to the die as possible in order to minimize bond wire length. Typical die-to-substrate spacing is 0.076mm to 0.152 mm (3 to 6 mils).

Handling Precautions

Follow these precautions to avoid permanent damage.

Storage: All bare die are placed in either Waffle or Gel based ESD protective containers, and then sealed in an ESD protective bag for shipment. Once the sealed ESD protective bag has been opened, all die should be stored in a dry nitrogen environment.

Cleanliness: Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.

Static Sensitivity: Follow ESD precautions to protect against ESD strikes.

Transients: Suppress instrument and bias supply transients while bias is applied. Use shielded signal and bias cables to minimize inductive pick-up.

0.102mm (0.004") Thick GaAs MMIC
Wire Bond
0.076mm (0.003")
RF Ground Plane
0.127mm (0.005") Thick Alumina Thin Film Substrate
Figure 1.

0.102mm (0.004") Thick GaAs MMIC
Wire Bond
0.076mm (0.003")
RF Ground Plane
0.150mm (0.005") Thick Moly Tab
0.254mm (0.010") Thick Alumina Thin Film Substrate
Figure 2.

General Handling: Handle the chip along the edges with a vacuum collet or with a sharp pair of bent tweezers. The surface of the chip has fragile air bridges and should not be touched with vacuum collet, tweezers, or fingers.
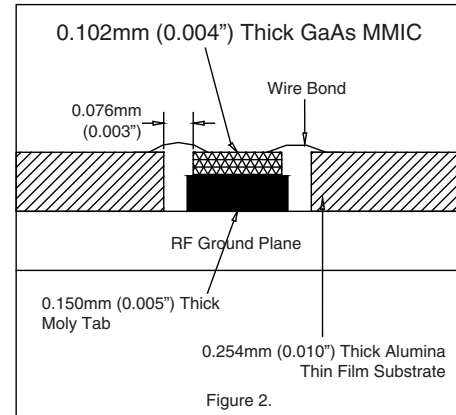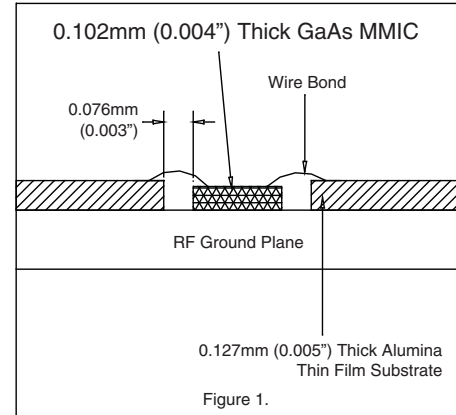
Mounting

The chip is back-metallized and can be die mounted with AuSn eutectic preforms or with electrically conductive epoxy. The mounting surface should be clean and flat.

Eutectic Die Attach: A 80/20 gold tin preform is recommended with a work surface temperature of 255 °C and a tool temperature of 265 °C. When hot 90/10 nitrogen/hydrogen gas is applied, tool tip temperature should be 290 °C. DO NOT expose the chip to a temperature greater than 320 °C for more than 20 seconds. No more than 3 seconds of scrubbing should be required for attachment.

Epoxy Die Attach: Apply a minimum amount of epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip once it is placed into position. Cure epoxy per the manufacturer's schedule.

Wire Bonding

Ball or wedge bond with 0.025mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31mm (12 mils).

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Notes:

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